

Continental Device India Limited

An IS/ISO 9002 and IECQ Certified Manufacturer





NPN SILICON EPITAXIAL TRANSISTORS



BC140, -6, -10, -16 BC141, -6, -10, -16 TO-39

Medium power amplifier & switching applications Complementary BC160 & BC161

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	BC140	BC141	UNITS
Collector -Emitter Voltage	VCE0	40	60	V
Collector -Base Voltage	VCBO	80	100	V
Emitter -Base Voltage	VEBO	7.0		V
Collector Current- Continuous	IC	1.0		Α
Power Dissipation@ Ta=25 deg C	PD	8.0		W
Derate Above 25 deg C		4.6		mW/deg C
Power Dissipation@ Tc=25 deg C	PD	3.7		W
Derate Above 25 deg C		20		mW/deg C
Operating & Storage Junction	Tj, Tstg	-65 to +200		deg C
Temperature Range	, ,			
THERMAL RESISTANCE				
Junction to Ambient	Rth(j-a)	200		deg C/W
Junction to Case	Rth(j-c)	35		deg C/W

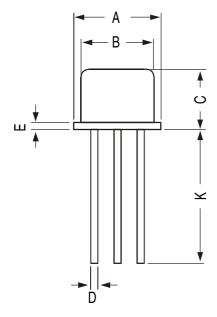
ELECTRICAL CHARACTERISTICS (Ta=25 deg C Unless Otherwise Specified)

DESCRIPTION (13	SYMBOL	Uniess Otherwise Spe	BC140		DC1/11	UNITS
		VOE 400 A VEE 0			BC141	
Collector -Emitter Voltage	VCES	VCE=100uA, VBE=0	>80		>100	V
	VCEO*	IC=30mA,IB=0	>40		>60	V
Emitter-Base Voltage	VEBO	IE=100uA, IC=0		>7.0		V
Collector-Cut off Current	ICES	VCE=60V, VBE=0		<100		nA
		Ta=150 deg C				
		VCE=60V, VBE=0		<100		uA
DC Current Gain	hFE*	IC=100mA,VCE=1V				
		BC140,BC141		40-400		
		Group-6		40-100		
		Group-10		63 to 160		
		Group-16		100 to 250		
		IC=1A,VCE=1V				
		BC140,BC141		typ 26		
		Group-6		typ 15		
		Group-10		typ 20		
		Group-16		typ 30		
Collector Emitter Saturation Voltage	VCE(Sat) *	C=1A, IB=0.1A		<1.0		V
Base Emitter on Voltage	VBE(on) *	IC=1A,VCE=1V		<2.0		V

BC140/141 UNITS	SYMBOL	ESCRIPTION
		YNAMIC CHARACTERISTICS
CE=10V >50 MHz	ft IC= f=20	urrent Gain Bandwidth Product
=1MHz <25 pF	Cob VCI	ut-Put Capacitance
f=1MHz <80 pF	Cib VEI	-Put Capacitance WITCHING CHARACTERISTICS
IB1=7.5 mA <250 ns	ton IC=	urn on time
IB1=IB2=7.5 mA <850 ns	toff IC=	urn off time
UC8> AIII C. 1=201=1 OI	ion ic=	arii oii tiine

^{*}Pulsed: Pulse Duration=300us, Duty Cycle=1%

TO-39 Metal Can Package

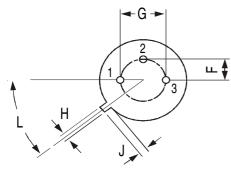


	וווים	141114	1417171		
	Α	8.50	9.39		
	В	7.74	8.50		
	С	6.09	6.60		
	D	0.40	0.53		
=	Е	1	0.88		
All dimensions are in mm	F	2.41	2.66		
	G	4.82	5.33		
	Н	0.71	0.86		
	J	0.73	1.02		
	K	12.70	_		
All d	L	42 DEG	48 DEG		
- '					

MIN

MAX

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PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX			
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt	
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20.0K	17" x 15" x 13.5"	32.0K	40 kgs	

Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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